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## Silicon Epitaxial Trench Pin Diode for Antenna Switching



ADE-208-949 (Z)

Rev. 0 Jul. 2000

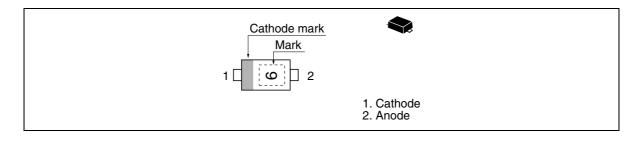
#### **Features**

- Adopting the trench structure improves low capacitance. (C = 0.45 pF max)
- Low forward resistance. (rf =  $2.5 \Omega \text{ max}$ )
- Low operation current.
- Super small Flat Package (SFP) is suitable for surface mount design.

#### **Ordering Information**

Type No.	Laser Mark	Package Code
HVD136	6	SFP

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit	
Peak reverse voltage	$V_{_{RM}}$	65	V	
Reverse voltage	V <sub>R</sub>	60	V	
Forward current	I <sub>F</sub>	100	mA	
Power dissipation	Pd	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature	Tstg	−55 to +125	°C	

#### **Electrical Characteristics**

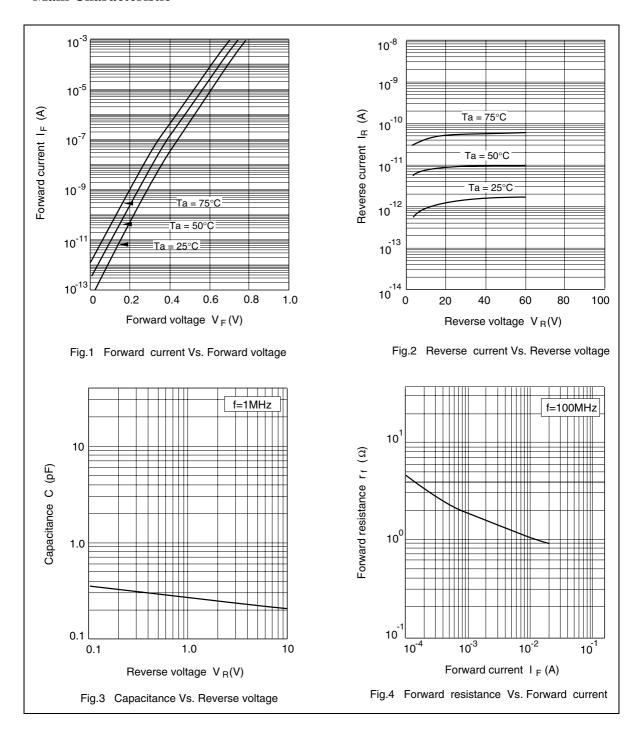
 $(Ta = 25^{\circ}C)$ 

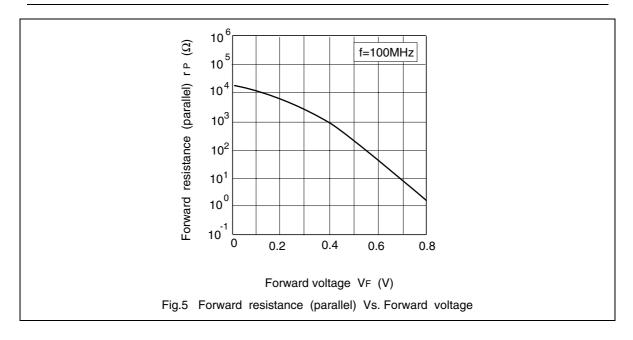
Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I <sub>R</sub>	_		0.1	μΑ	V <sub>R</sub> = 60 V
Forward voltage	V <sub>F</sub>	_	_	0.9	V	I <sub>F</sub> = 2 mA
Capacitance	С	_		0.45	pF	V <sub>R</sub> = 1 V, f = 1 MHz
Forward resistance	r <sub>f</sub>	_	_	2.5	Ω	I <sub>F</sub> = 2 mA, f = 100 MHz
ESD-Capability *1	_	100		_	V	$C = 200 \text{ pF}, R = 0 \Omega$ , Both forward and reverse direction 1 pulse.

Notes : 1. Failure criterion ;  $I_R > 100 \text{ nA}$  at  $V_R = 60 \text{ V}$ 

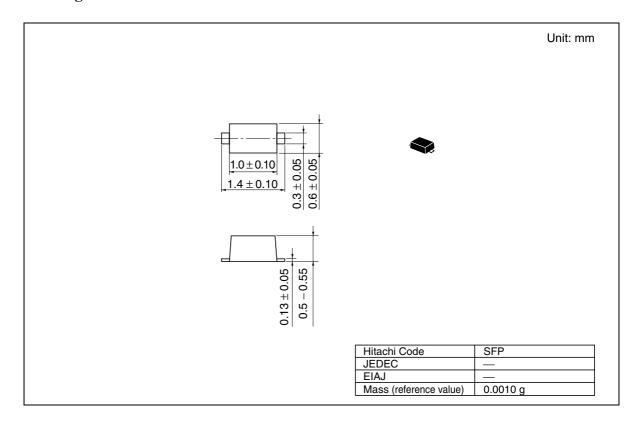
2. Please do not use the soldering iron due to avoid high stress to the SFP package.

#### **Main Characteristic**





## **Package Dimensions**



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